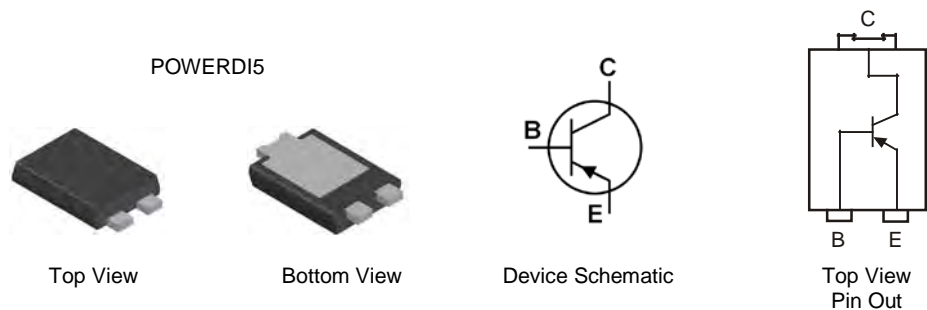


## Features

- $BV_{CEO} > -40V$
- $I_C = -3A$  high Continuous Collector Current
- $I_{CM} = -6A$  Peak Pulse Current
- 43% smaller than SOT223; 60% smaller than TO252
- Maximum Height Just 1.1mm
- Rated up to 3.2W
- Low Saturation, High Gain Transistor,
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

## Mechanical Data

- Case: POWERDI5
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.093 grams (approximate)

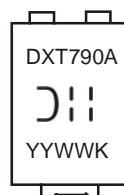


## Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DXT790AP5-13	DXT790A	13	16	5,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>

## Marking Information



- DXT790A = Product Type Marking Code  
 J11 = Manufacturers' Code Marking  
 K = Factory Designator  
 YYWW = Date Code Marking  
 YY = Last Two Digits of Year (ex: 09 for 2009)  
 WW = Week code (01 to 53)

**Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

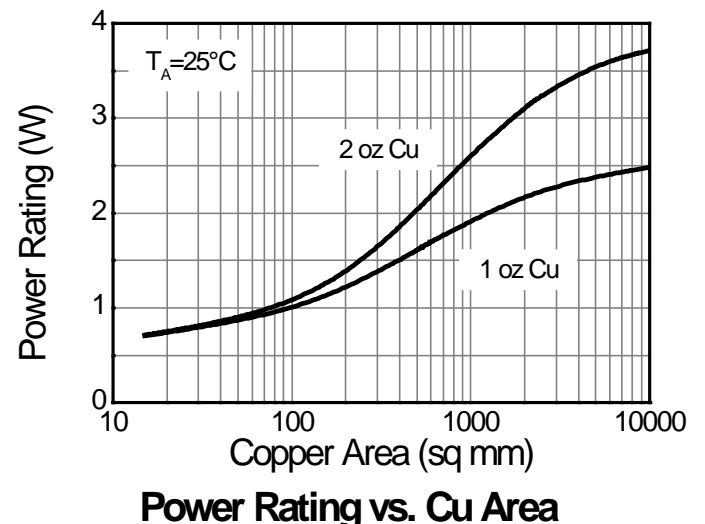
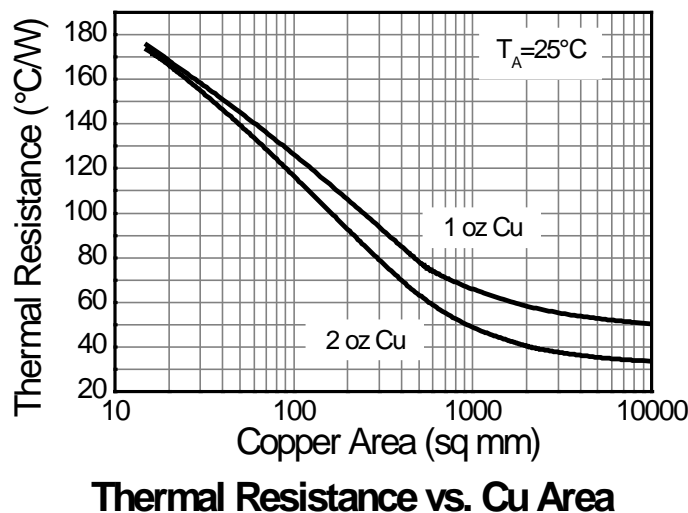
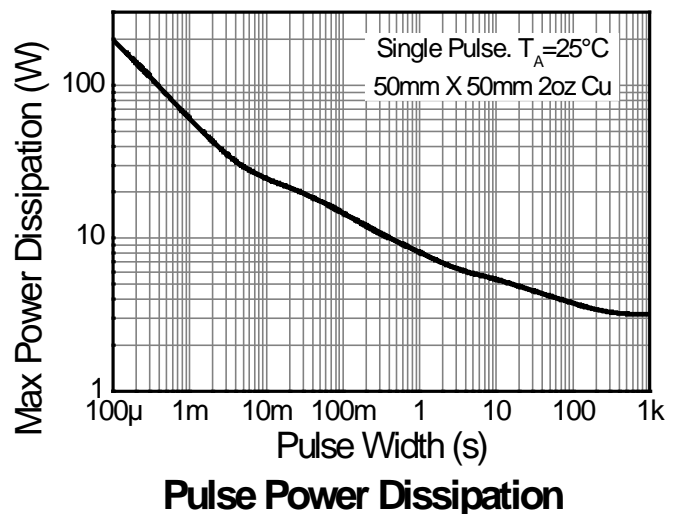
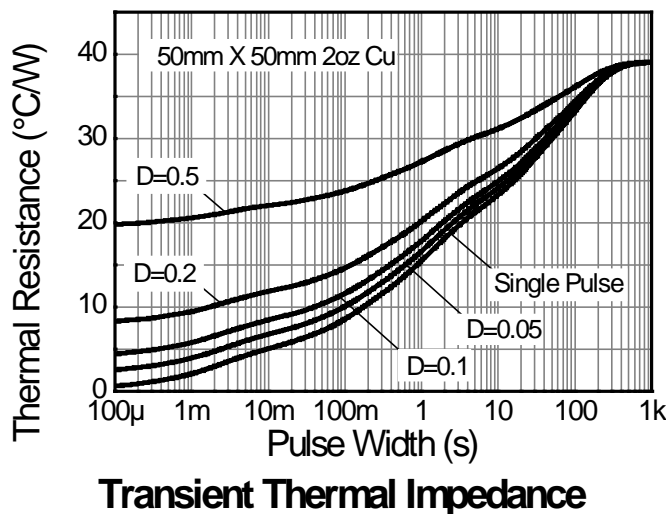
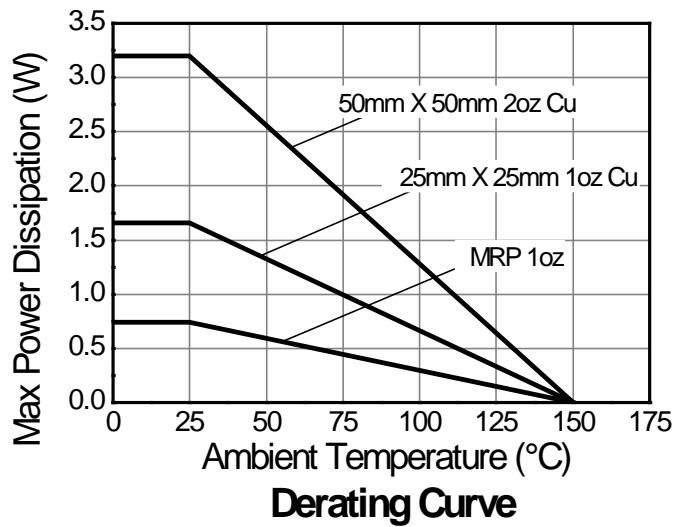
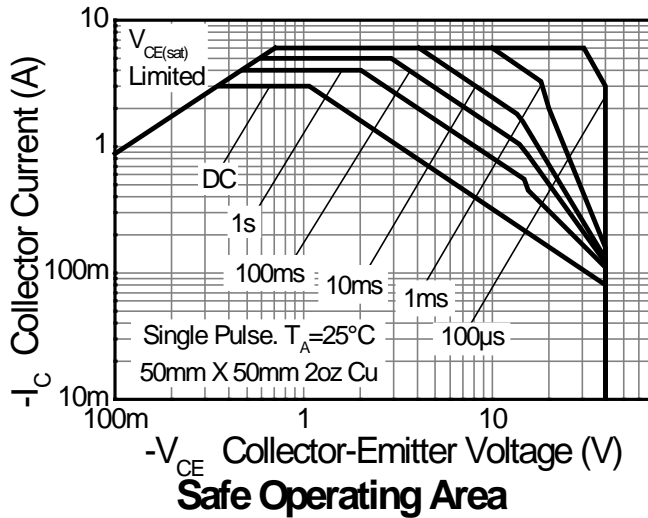
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-40	V
Emitter-Base Voltage	V <sub>EBO</sub>	-6	V
Continuous Collector Current	I <sub>C</sub>	-3	A
Peak Pulse Current	I <sub>CM</sub>	-6	A
Base Current	I <sub>B</sub>	-0.5	A

**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	P <sub>D</sub>	(Note 5)	3.2
		(Note 6)	1.7
		(Note 7)	0.74
Thermal Resistance, Junction to Ambient Air	R <sub>θJA</sub>	(Note 5)	39
		(Note 6)	75
		(Note 7)	169
Thermal Resistance, Junction to Lead	R <sub>θJL</sub>	8.9	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

- Notes:
5. For a device mounted with the exposed collector pad on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
  6. Same as note (5), except the device is mounted on 25mm x 25mm 1oz copper.
  7. Same as note (5), except the device is mounted on minimum recommended pad (MRP) layout 1oz copper.
  8. Thermal resistance from junction to solder-point (on the exposed collector pad).

**Thermal Characteristics and Derating Information**

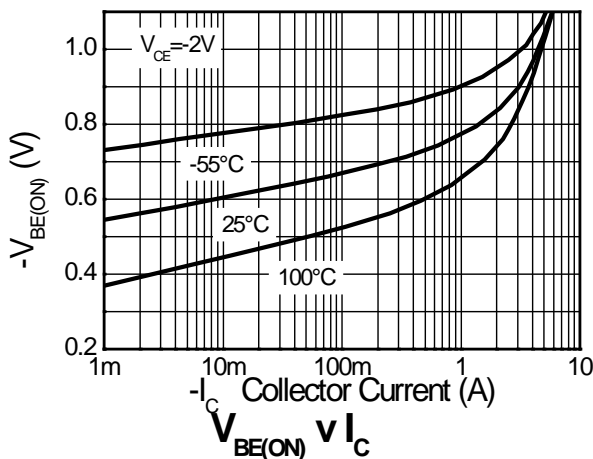
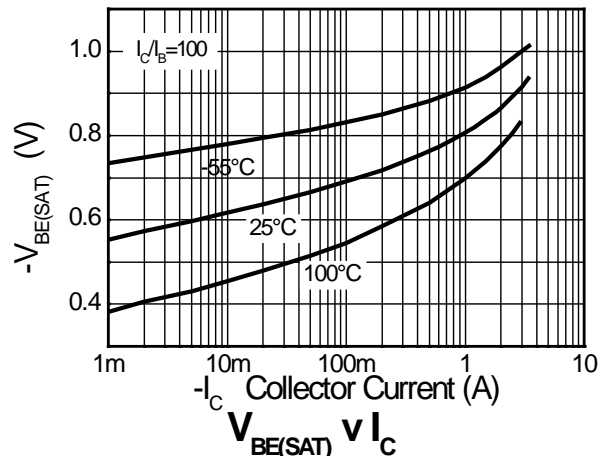
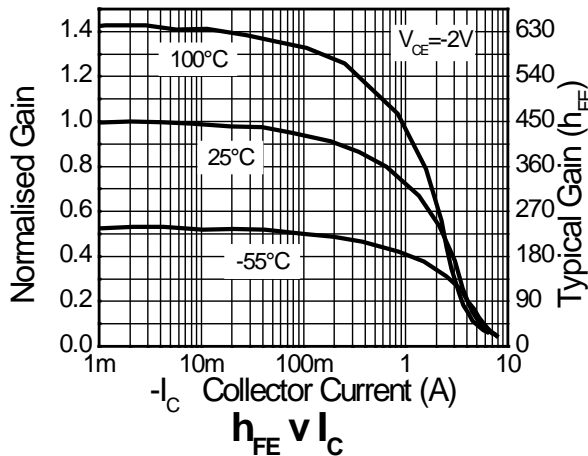
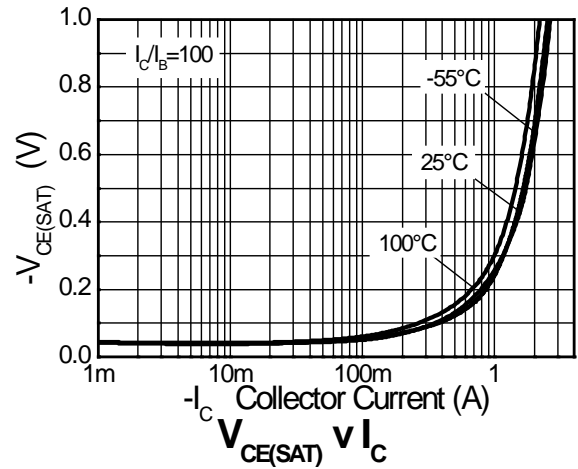
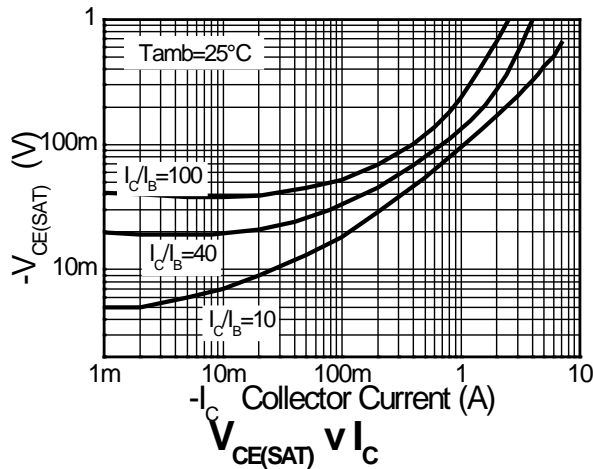


**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS</b>						
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-50	—	—	V	I <sub>C</sub> = -100μA, I <sub>E</sub> = 0
Collector-Emitter Breakdown Voltage (Note 8)	BV <sub>CEO</sub>	-40	—	—	V	I <sub>C</sub> = -10mA, I <sub>B</sub> = 0
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-6	—	—	V	I <sub>E</sub> = -100μA, I <sub>C</sub> = 0
Collector Cutoff Current	I <sub>CBO</sub>	—	—	-20	nA	V <sub>CB</sub> = -30V, I <sub>E</sub> = 0
Collector Cutoff Current	I <sub>CES</sub>	—	—	-20	nA	V <sub>CB</sub> = -30V, V <sub>BE</sub> = 0
Emitter Cutoff Current	I <sub>EBO</sub>	—	—	-20	nA	V <sub>EB</sub> = -4V, I <sub>C</sub> = 0
<b>ON CHARACTERISTICS (Note 8)</b>						
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	—	—	-170	mV	I <sub>C</sub> = -0.5A, I <sub>B</sub> = -5mA
		—	—	-350		I <sub>C</sub> = -1A, I <sub>B</sub> = -10mA
		—	—	-450		I <sub>C</sub> = -2A, I <sub>B</sub> = -50mA
		—	—	-450		I <sub>C</sub> = -3A, I <sub>B</sub> = -300mA
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	—	—	-1.15	V	I <sub>C</sub> = -3A, I <sub>B</sub> = -300mA
Base-Emitter Turn-On Voltage	V <sub>BE(on)</sub>	—	—	-1.0	V	I <sub>C</sub> = -3A, V <sub>CE</sub> = -2V
DC Current Gain	h <sub>FE</sub>	300	—	800	—	I <sub>C</sub> = -10mA, V <sub>CE</sub> = -2V
		250	—	—		I <sub>C</sub> = -500mA, V <sub>CE</sub> = -2V
		200	—	—		I <sub>C</sub> = -1A, V <sub>CE</sub> = -2V
		150	—	—		I <sub>C</sub> = -2A, V <sub>CE</sub> = -2V
		80	—	—		I <sub>C</sub> = -3A, V <sub>CE</sub> = -2V
<b>AC CHARACTERISTICS</b>						
Transition Frequency	f <sub>T</sub>	100	—	—	MHz	I <sub>C</sub> = -50mA, V <sub>CE</sub> = -5V, f = 50MHz
Output Capacitance	C <sub>obo</sub>	—	24	—	pF	V <sub>CB</sub> = -10V, f = 1MHz
Switching Times	t <sub>on</sub>	—	35	—	ns	I <sub>C</sub> = -500mA, V <sub>CC</sub> = -10V,
	t <sub>off</sub>	—	600	—	ns	I <sub>B1</sub> = -I <sub>B2</sub> = -50mA

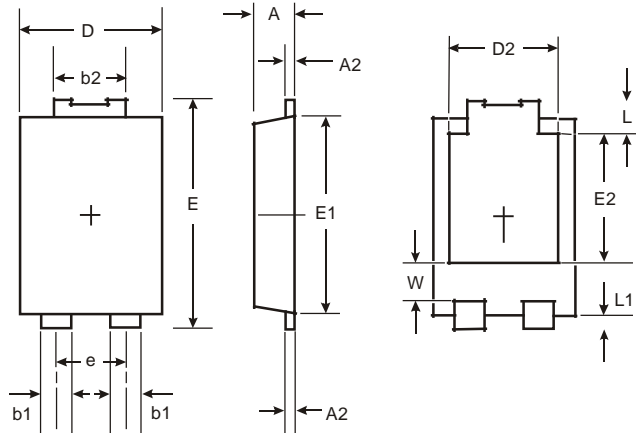
Notes: 8. Measured under pulsed conditions. Pulse width • 300μs. Duty cycle • 2%.

**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



**Package Outline Dimensions**

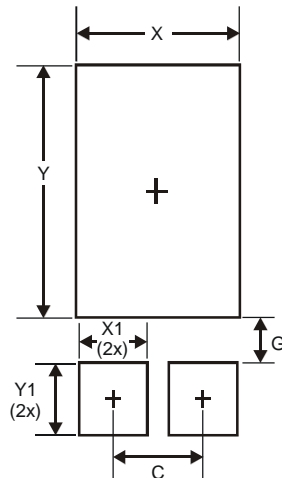
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



POWERDI5		
Dim	Min	Max
A	1.05	1.15
A2	0.33	0.43
b1	0.80	0.99
b2	1.70	1.88
D	3.90	4.05
D2	3.054 Typ	
E	6.40	6.60
e	1.84 Typ	
E1	5.30	5.45
E2	3.549 Typ	
L	0.75	0.95
L1	0.50	0.65
W	1.10	1.41
<b>All Dimensions in mm</b>		

**Suggested Pad Layout**

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
C	1.840
G	0.852
X	3.360
X1	1.390
Y	4.860
Y1	1.400

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